

RJK1002DPN-E0

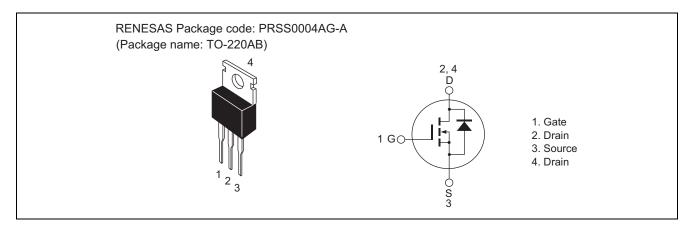
N-Channel MOS FET 100 V, 70 A, 7.6 m Ω

R07DS0620EJ0200 Rev.2.00 Aug 24, 2012

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 6.0 \text{ m}\Omega$ typ. (at $V_{GS} = 10 \text{ V}$)
- Package TO-220AB

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	100	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	70	А
Drain peak current	I _{D (pulse)} Note1	210	А
Body-drain diode reverse drain current	I _{DR}	70	А
Avalanche current	I _{AP} Note2	35	А
Avalanche energy	E _{AS} Note2	123	mJ
Channel dissipation	Pch Note3	150	W
Channel to case thermal impedance	θch-c	0.83	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at L = 100 μ H, Tch = 25°C, Rg \geq 50 Ω ,
- 3. Tc = 25°C

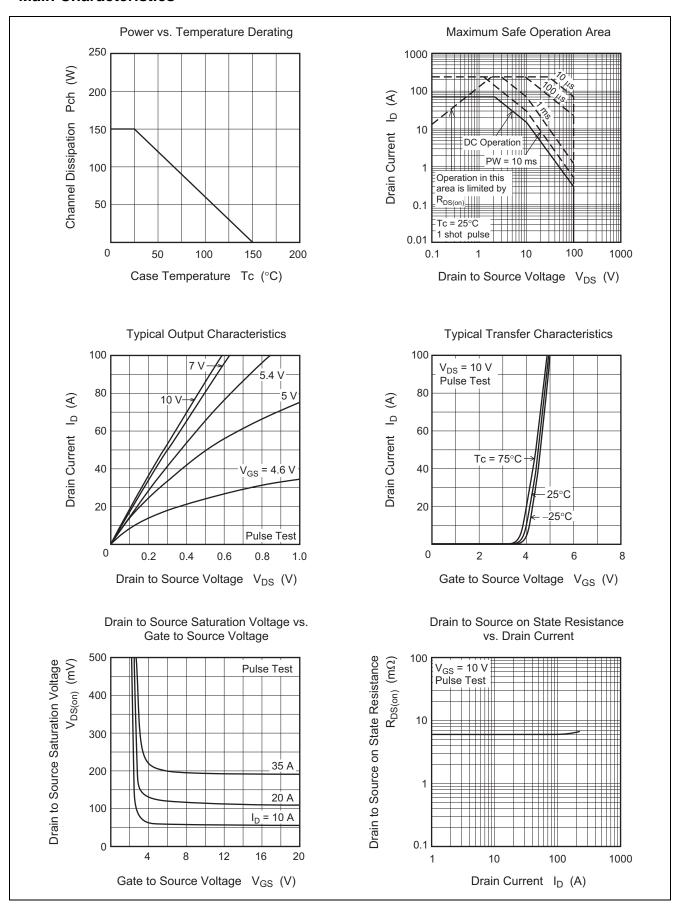
Electrical Characteristics

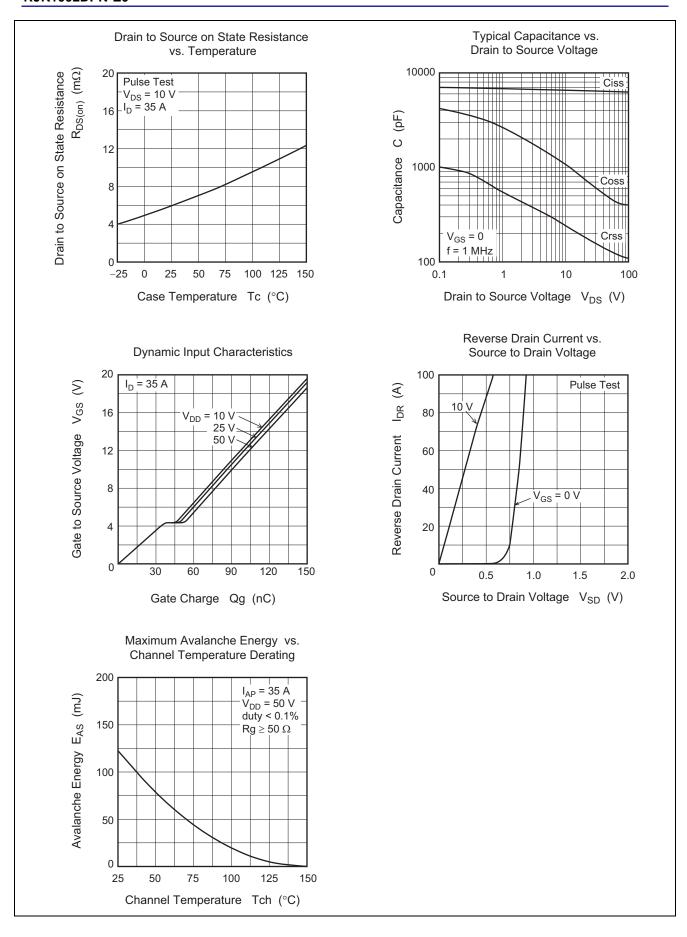
 $(Ta = 25^{\circ}C)$

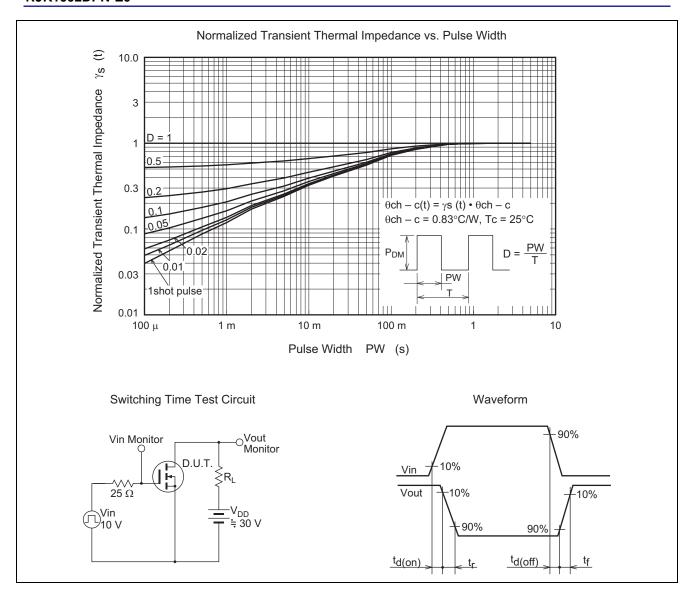
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	_	_	V	$I_D = 10 \text{mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	6.0	7.6	mΩ	$I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Forward transfer admittance	y _{fs}		135	_	S	$I_D = 35 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		6450	_	pF	V _{DS} = 10 V
Output capacitance	Coss		1000	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	240	_	pF	
Gate Resistance	Rg	_	1.5	_	Ω	
Total gate charge	Qg	_	94	_	nC	V _{DD} = 50 V
Gate to source charge	Qgs	_	33	_	nC	$V_{GS} = 10 \text{ V},$ $I_D = 35 \text{ A}$
Gate to drain charge	Qgd	_	19	_	nC	
Turn-on delay time	t _{d(on)}	_	40	_	ns	V _{GS} = 10 V
Rise time	t _r	_	13	_	ns	$\begin{split} I_D &= 35 \text{ A} \\ V_{DD} &\cong 30 \text{ V} \\ Rg &= 4.7 \Omega \end{split}$
Turn-off delay time	$t_{d(off)}$	_	80	_	ns	
Fall time	t _f	_	13	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.85	1.5	V	$I_F = 70 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	65	_	ns	I _F = 70 A, V _{GS} = 0
						di _F /dt = 100 A/μs

Notes: 4. Pulse test

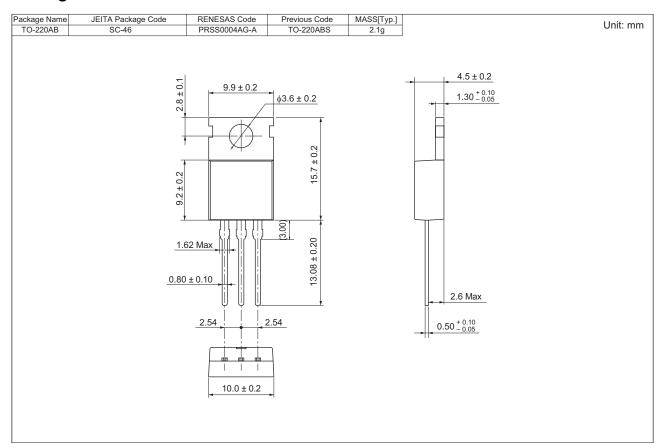
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK1002DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 nunLu Haidian District, Beijing 100083, P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.

เกลาเออออ Erectionius เพลาสู่ysta 3นที.bnu. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: 482-2-588-3737, Fax: 482-2-588-5141